



#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on) max</sub>	Ι <sub>D</sub> T <sub>A</sub> = +25°C
2017	15mΩ @ V <sub>GS</sub> = 10V	8.4A
30V	18mΩ @ V <sub>GS</sub> = 4.5V	7.7A

#### Description

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

#### Applications

- DC-DC Converters
- Power Management Functions
- Backlighting

# Features and Benefits

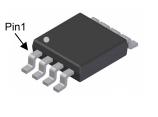
- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

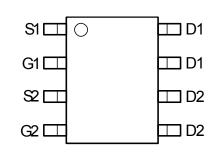
**30V DUAL N-CHANNEL ENHANCEMENT MODE MOSFET** 

- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

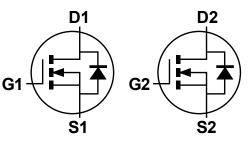
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (approximate)





Top View

Pin Configuration



Equivalent Circuit

### Ordering Information (Note 4)

Top View

Part Number	Case	Packaging
DMN3015LSD-13	SO-8	2,500/Tape & Reel

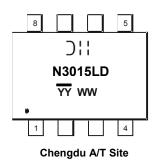
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



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 N3015LD
 YY WW

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 Shanghai A/T Site

)',' = Manufacturer's Marking
N3015LD = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 14 = 2014)
WW = Week (01 - 53)
YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



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#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units V			
Drain-Source Voltage	V <sub>DSS</sub>	30				
Gate-Source Voltage			V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	8.4 6.8	А	
	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	11.0 9.0	А	
Maximum Body Diode Forward Current (Note 6)			ls	2.5	A	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	80	A	
Avalanche Current (Notes 7) L = 0.1mH			I <sub>AS</sub>	22	A	
Avalanche Energy (Notes 7) L = 0.1mH			E <sub>AS</sub>	25	mJ	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Bower Dissinction (Note E)	T <sub>A</sub> = +25°C	Р	1.2	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.8	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	Devi	102	°C/W
	t<10s	R <sub>0JA</sub>	62	
Total Dever Dissinction (Note 6)	T <sub>A</sub> = +25°C	P	1.6	W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	1.0	
Thermal Desistance Junction to Ambient (Note 6)	Steady state	D	78	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	47	
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	14.5	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30		_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)				•			
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3	—	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	8	15	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 12A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	12	18	11152	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.0	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A	
DYNAMIC CHARACTERISTICS (Note 9)				•			
Input Capacitance	C <sub>iss</sub>		1415	—			
Output Capacitance	Coss		119		pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	82	_			
Gate Resistance	R <sub>G</sub>	_	2.6	3.2	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	11.3	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	25.1	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	—	3.5	_	no	V <sub>DS</sub> = 15V, I <sub>D</sub> = 12A	
Gate-Drain Charge	Q <sub>gd</sub>	_	3.6	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	4.8	_			
Turn-On Rise Time	tr		16.5	_	nS	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V,	
Turn-Off Delay Time	t <sub>D(off)</sub>		26.1		ns	$R_L$ = 1.25Ω, $R_G$ = 3Ω,	
Turn-Off Fall Time	tf	_	5.6	_			
Body Diode Reverse Recovery Time	t <sub>rr</sub>		8.5	_	nS	I <sub>S</sub> = 12A, dl/dt = 500A/µs	
Body Diode Reverse Recovery Charge	Qrr		7.0	_	nC	I <sub>S</sub> = 12A, dl/dt = 500A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. UIS in production with L = 0.1mH, starting  $T_A = +25^{\circ}$ C.

8. Short duration pulse test used to minimize self-heating effect.

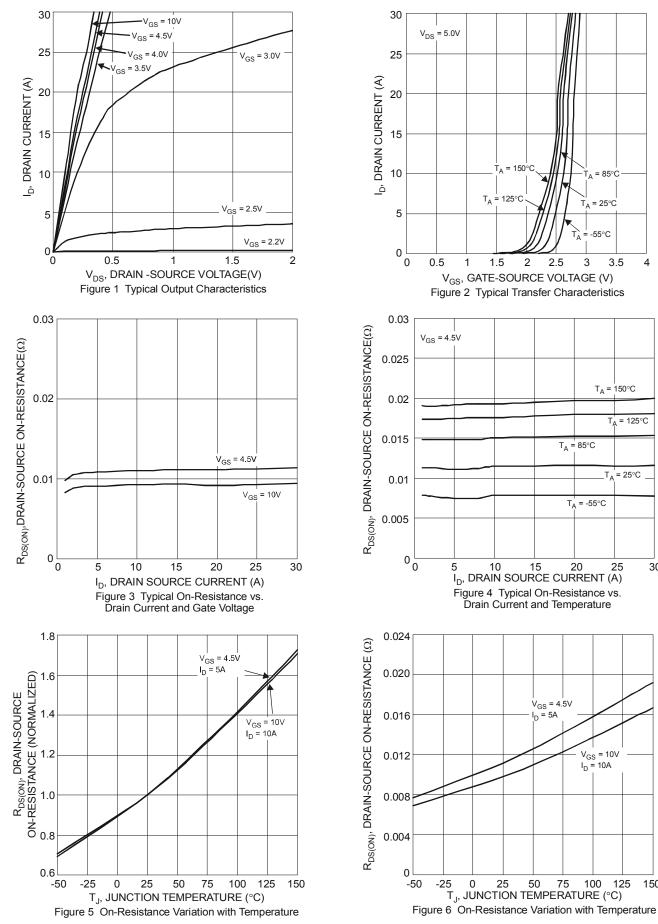
9. Guaranteed by design. Not subject to product testing.



#### DMN3015LSD

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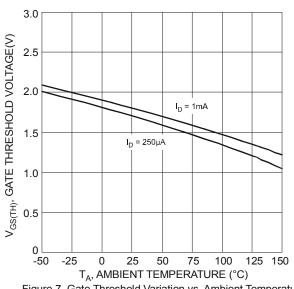
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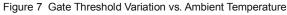
DMN3015LSD Document number: DS36300 Rev. 2 - 2

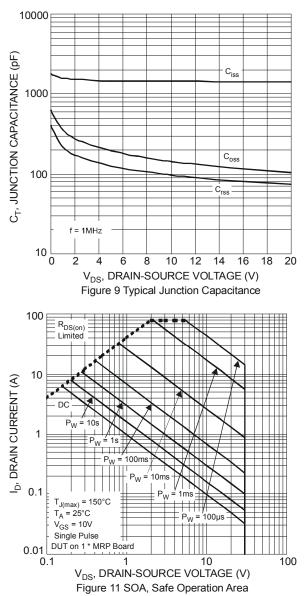
3 of 6 www.diodes.com 150

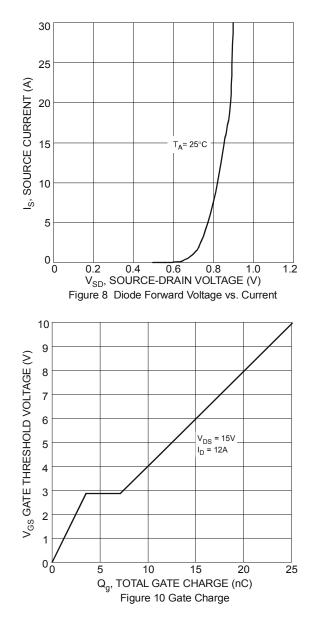


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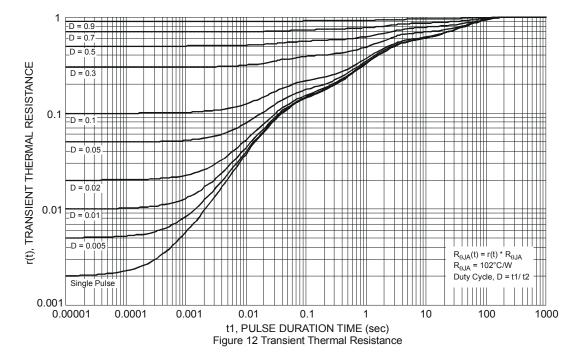






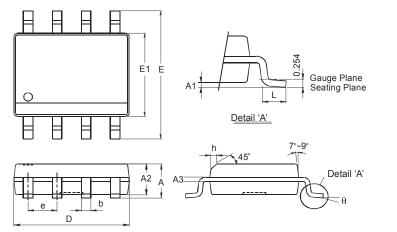






# Package Outline Dimensions

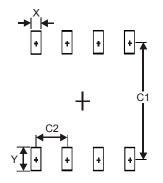
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
E	5.90	6.10			
E1	3.85 3.95				
е	1.27 Typ				
h	-	0.35			
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27



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